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**Trapped Ions 2:
Scalability & quantum metrology**

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Outline 

Ion trap scalability


- Challenge for quantum technology
- Example systems under study
- Case study of a microtrap

Trapped ions for precision measurements

- Atomic clocks
- Variation of fundamental constants
- Quantum logic clock



1. Ion trap scalability


Ion trap quantum computing 


Power of quantum information processing

- as problem size grows, required resources grow in manageable way
- useful technology must control large quantum systems
- in practice this means thousands of qubits (for now)

First proposal for trapped ion QIP

- Cirac & P. Zoller, PRL 74, 4091 (1995)
- string of ions in a single trap
- qubit logic levels: electronic states
- mutual Coulomb interaction: mechanism for transferring quantum information between ions
- many more details from lectures of Christian Roos




DiVincenzo Criteria 

Necessary conditions for any viable QIP technology platform

- 1 a scalable physical system of well-characterised qubits
- 2 the ability to initialise the state of the qubits to a simple state
- 3 long (relative) decoherence times
- 4 a universal set of quantum gates
- 5 a qubit-specific measurement capability

Necessary conditions for QIP “networkability”

- 1 the ability to interconvert stationary and flying qubits
- 2 the ability to faithfully transmit flying qubits between specified locations

Scalability 

Scaling to large number of ions

- single trap: presents huge technical difficulties
- probably limited to $\sim 10 \rightarrow \sim 20$ ions in practice
- centre of mass mode: ω_c breathing mode: $\sqrt{3}\omega_c$

“Architecture for a large-scale ion trap quantum computer”
D Kielpinski, C Monroe, D J Wineland, Nature, 417, 709 (2002)

Quantum charged-coupled device (QCCD)

- architecture consisting of many interconnected traps
- few ions in any one trap
- shuttle ions between traps
- uses quantum manipulation techniques already developed

Quantum CCD

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"Architecture for a large-scale ion trap quantum computer"
D Kielpinski, C Monroe, D J Wineland, Nature, 417, 709 (2002)

- segmented array of many interconnected ion traps
- QI held in memory zone
- shuttle ions to interaction zone
- ions held close together
→ Coulomb coupling
- focused laser drives entangling gate
- ions transported to other zone
- ready for next operation

The diagram shows a segmented array of ion traps. It features two 'memory zones' at the top and bottom, and an 'interaction zone' in the middle. Yellow lines represent the paths of ions being shuttled between these zones.

Segmented ion trap arrays: examples

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Many different technical approaches.....

3D, Au on Al₂O₃

F. Schmidt-Kaler

Surface electrode trap

D. Lucas

3D GaAs

C. Monroe
W. Hensinger

3D, Au on SiO₂

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.... by a number of different groups

Hensinger (Sussex) group review: M D Hughes, et al, arXiv:1101.3207v2 [quant-ph]

Gold on alumina microtrap

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Al₂O₃ wafer

- laser-machined electrode structure
- evaporate Au coating
- electroplate to ~few μm thickness
- assemble layers into 3D structure

Very successful in QIP demonstrations

- M D Barrett *et al.* Nature 429, 737 (2004): teleportation
- many other QIP experiments from Wineland group

Junction: W K Hensinger *et al.* Appl Phys Lett 88, 034101 (2006)

- "T"-junction and 2D array: 3-layer trap

State of the art: R B Blakestad *et al.* Phys Rev Lett 102, 153002 (2009)

- "X"-junction and 2D array: high fidelity transport

The micrograph shows a 3D structure with a 'Loading Zone' and a '100 μm' scale bar. Dimensions of 400 μm and 250 μm are also indicated.

courtesy: D. Wineland, NIST

Gold on alumina microtrap

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F. Schmidt-Kaler, Univ. Mainz

- 125 μm wafers, 250 μm wide processor zone, 500 μm wide loading zone

The micrograph shows a 3D structure with a loading zone and a processor zone.

courtesy: F Schmidt-Kaler

$\omega/2\pi \leq 2.0$ MHz
 $\omega/2\pi \leq 1.2$ MHz
 trap depth = 0.75 eV

S A Schulz, *et al.*,
 New J Phys 10, 045007 (2008)

Surface electrode ion trap arrays

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Wineland group: S. Seidelin, *et al.* Phys Rev Lett 96, 253003 (2006)

All electrodes lie in a single plane (2D)

- significant simplification in fabrication

D Lucas (Oxford): D T C Allcock, *et al.*, New J Phys 12, 053026 (2010)

The diagram shows four steps: a) Evaporation of Ag/Ti seed layer, b) Lithographic definition of electrode template, c) Electroplating of gold electrodes, d) Template and seed layer etch. A legend identifies Silver, Titanium, Gold, Photoresist, and Quartz.

courtesy: D Lucas

Surface electrode ion trap arrays

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D Lucas, Oxford

The micrograph shows a 3D structure with a loading zone and a processor zone.

courtesy: D Lucas

$r_0 = 150$ μm
 $\Omega_{RF}/2\pi = 25.8$ MHz
 $112 \text{ V} \leq U_{RF} \leq 223 \text{ V}$
 $2.0 \text{ MHz} \leq \omega/2\pi \leq 4.0 \text{ MHz}$
 $300 \text{ kHz} \leq \omega/2\pi \leq 1.2 \text{ MHz}$
 Trap depth: 47 to 188 meV
 Ion Lifetime (typical): 5 min

D T C Allcock, *et al.*,
 New J Phys 12, 053026 (2010)

Surface electrode ion trap arrays

D Moehring, D Stick, M Blaine, (Sandia Labs)

courtesy: D L Moehring

Single ion shuttling

- 10 electrodes, 770 μm , 10^6 times, without loss
- 1.5 km @ 0.77 m/s

D Stick, *et al*,
arXiv:1008.0990v2 [physics.ins-det]

Surface electrode ion trap arrays

D Moehring, D Stick, M Blaine, (Sandia Labs)

“Y”-shaped junction trap

- High-fidelity single ion shuttling
- Ion string: splitting, swapping, recombining

courtesy: D L Moehring

D L Moehring, *et al*, arXiv:1105.1834v1 [quant-ph]

Monolithic 3D microtrap

Monroe group: D. Stick, *et al*, Nature Phys, 2, 36 (2006)

MEMS GaAs microtrap

- AlGaAs & GaAs layers
- GaAs conductor for electrodes

Segment width = 130 μm
Aperture width = 60 μm
Layer thickness = 2 \rightarrow 4 μm
Trap depth \sim 80 meV
Ion lifetime (uncooled) \sim 100 ms

courtesy: Winni Hensinger & Chris Monroe

MEMS GaAs 3D microtrap

Monroe group: D. Stick, *et al*, Nature Phys, 2, 36 (2006)

Segment width = 130 μm
Aperture width = 60 μm
Layer thickness = 2 \rightarrow 4 μm
Trap depth \sim 80 meV
Ion lifetime (uncooled) \sim 100 ms

courtesy: Winni Hensinger & Chris Monroe

Other activity

Wineland group (NIST), surface traps:

- J M Amini *et al*, New J Phys 12, 033031 (2010)
- 150 zones, 6 “Y” junctions
- hexagonal circuit configuration

Wineland group (NIST), “degenerate” silicon traps:

- J Britton *et al*, Appl Phys Lett 95, 173102 (2009)
- surface and 3D (assembled) configurations

Chuang group (MIT) group, “surface” traps:

- J Labaziewicz, *et al*, Phys Rev Lett 100, 013001 (2008)
- silver on quartz
- cryogenic temperatures: reduced heating rate

Measured heating rates

Heating is due to electric field noise on electrodes

- Spectral density of noise at ω_z

$$\dot{n} = \frac{e^2 S_E(\omega_z)}{4m\hbar\omega_z}$$

$$S_E(\omega) \propto \frac{1}{d^4}$$

Graph courtesy of Winni Hensinger, Sussex

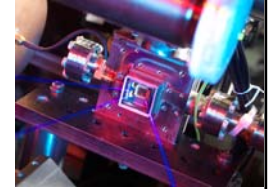
Turchette *et al*, Phys. Rev. A 61, 063418 (2000)
Deslauriers *et al*, Phys. Rev. A 70, 043408 (2004)

2. Microtrap case-study

A microfabricated ion trap

From idea to reality

- Concept of the microtrap
- Design considerations
- Fabrication
- How does it perform?
- First ion trapping results
- Future uses



Microtrap concept: 1

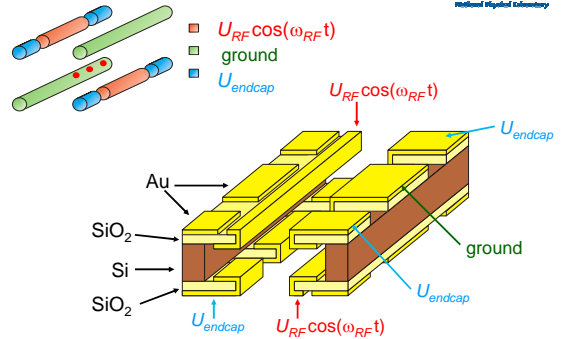
Aims: desirable attributes

- long ion storage times → easier trap operation
- high motional frequencies → fast gates & qubit processing
- precise geometry → ideal behaviour
- scalability → towards large number of ions
- minimised dielectric surfaces → minimum stray charges

Requirements

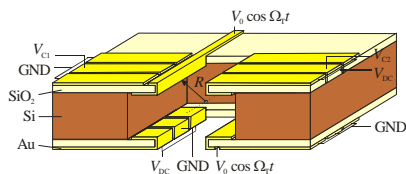
- 3D, unit-aspect ratio geometry
- monolithic fabrication process
- lithographic techniques extended to 3D
- low rf power dissipation: eg Au on SiO₂

Microtrap concept: 2



M Brownnutt, G Wilpers, P Gill, R C Thompson, AS, New. J. Phys. 8, 232 (2006)

Microtrap concept: 2



- highly doped silicon wafer (350 μm) → grounded spacer surface
- oxidised surfaces (15 μm fused silica) → low loss insulator
- gold electrodes in 3D → low loss conductor
- efficient electrode geometry
- dielectric surfaces covered

Brownnutt, et al, N J Phys. 8, 232 (2006)

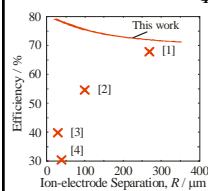
Trap potential modelling

Use finite element modelling (2 & 3D)

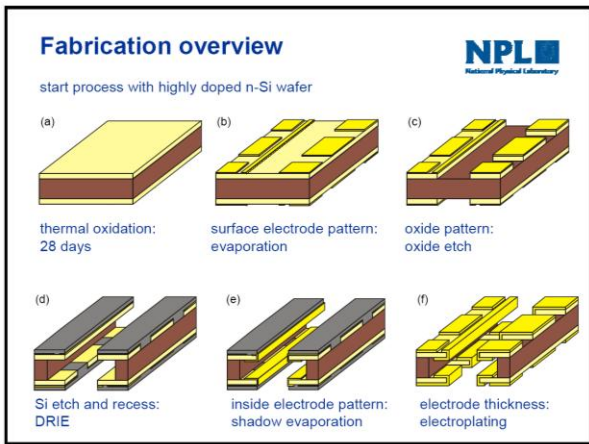
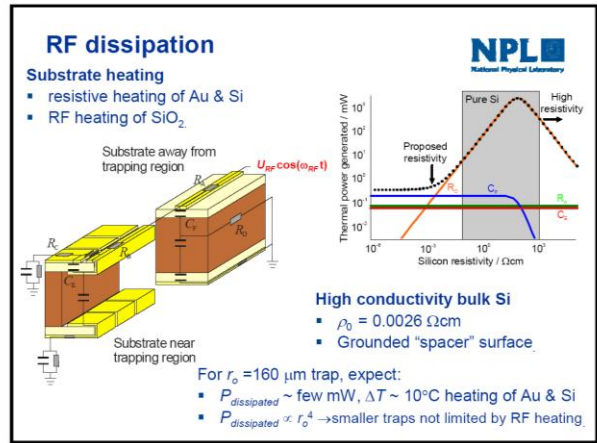
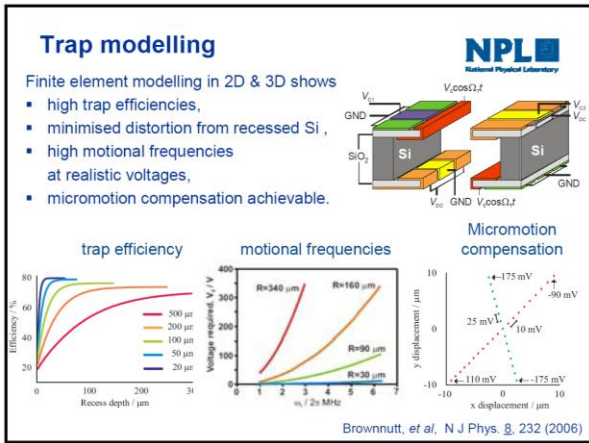
Trap Efficiency, η_{trap}

- compare microtrap potential with a quadrupole potential (hyperbolic electrodes) of comparable size.
- ratio of quadrupole part of potential in a microtrap to a hyperbolic trap potential of same r_0

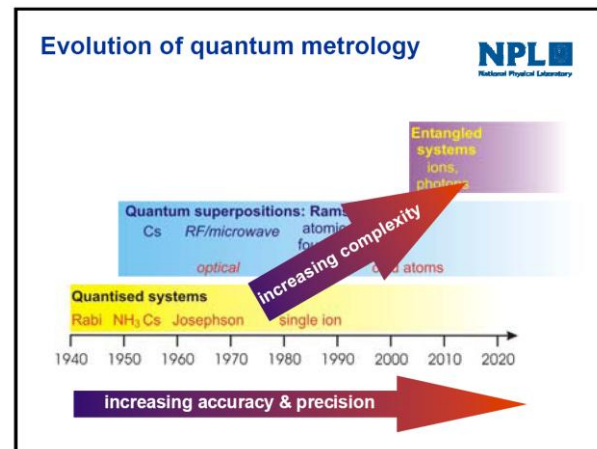
$$\eta_{trap} = \frac{\Phi_{microtrap}^{(2)}}{\Phi_{hyperbolic}} \quad \omega_r = \eta_{trap} \frac{eU_{RF}}{\sqrt{2m\omega_{RF}} r_0^2}$$



- [1] 2-layer Al₂O₃ trap. (Wineland)
M.A. Rowe *et al.*, Quant. Inf. Comp. 2, 257 (2002)
- [2] 3-layer Al₂O₃ trap. (Monroe)
W.K. Hensinger *et al.*, App Phys Lett 88, 034101 (2006)
- [3] GaAs High aspect ratio trap. (Monroe)
D. Stick *et al.*, Nature Physics 2, 36 (2006)
- [4] Surface Trap. (Wineland).
S. Siedelin *et al.*, PRL 96, 253003 (2006)



3. Trapped ion atomic clocks



Atomic clocks

Quantised energies in atomic systems

- $E = \hbar\omega_o$: natural definition of frequency & time
- References at microwave and optical frequencies

Atomic energies are very sensitive to perturbations!

Some definitions

Short term (in)stability

- a measure of the extent by which ν_{out} fluctuates about ν_o
- ν_{out} is the locked local oscillator (i.e. laser) frequency
- dominated by the local oscillator

$$\sigma(\tau) = \frac{\Delta\nu}{\pi\nu_o} \cdot \left[\frac{T}{N\tau} \right]^{\frac{1}{2}}$$

instability atomic Q-factor signal-to-noise

$$Q = \frac{\nu_o}{\Delta\nu} \quad (s/n) = \left[\frac{N\tau}{T} \right]^{\frac{1}{2}}$$

- T is cycle time (time to make a single correction to ν_{laser})
- N is no. of absorbers detected in a cycle, τ is averaging time

Accuracy

- How well does ν_{out} agree with the unperturbed theoretical ν_o ?
- dominated by longer-term reproducibility of the atomic reference
- absolute uncertainty is measured against primary Cs standard

Cs beam clock

L Essen & J V L Parry at NPL:
Phil. Trans. R. Soc. A **250**, 40 (1957) $L = 0.5 \text{ m}$ $\delta\nu/\nu = 1 \times 10^{-10}$

Increase the distance between resonators

- Increase the free precession time T \Rightarrow reduce linewidth

Nature **184**, 1792 (1959) $L = 2.8 \text{ m}$ $\delta\nu/\nu = 1 \times 10^{-11}$

Why optical?

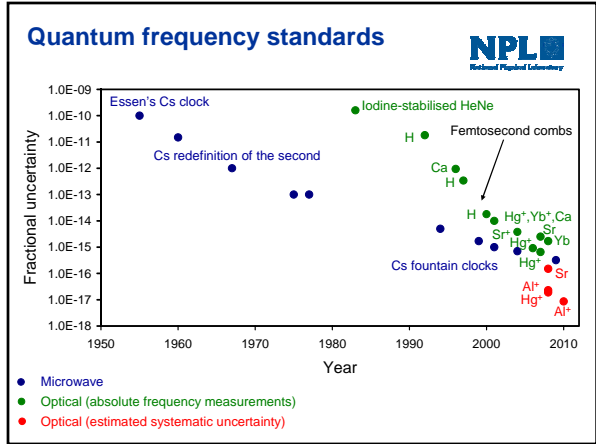
Current primary frequency standards

- based on 9.2 GHz hyperfine transition in ^{133}Cs atoms (fountain)
- accuracy $\sim 10^{-15}$ with >1 day of averaging time
- systematic $\delta\nu/\nu = 4.1 \times 10^{-16}$ eg: K. Szymaniec, et al, Metrologia **47**, 363 (2010)

$$\text{clock instability: } \sigma \propto \frac{\Delta\nu}{\nu_o} \cdot \frac{1}{(s/n)}$$

Optical frequency standards

- based on forbidden transitions in atomic particles, $\Delta\nu \sim 1 \text{ Hz}$
- frequencies: $\nu \sim 10^{15} \text{ Hz}$
- optical resonance Q-factor: $\Delta\nu/\nu \sim 10^{15}$
- results in better stabilities than microwave clocks
- projected uncertainty: can be down to 10^{-17} and better



Why ions for a reference?

A single, laser-cooled, trapped ion is...

- an isolated particle, virtually at rest, unperturbed by its environment

Desirable features

- laser cooled \rightarrow no Doppler-broadening
- Lamb-Dicke confinement \rightarrow minimised 2nd order Doppler shift
- no E-field at trap centre \rightarrow minimised perturbations
- UHV \rightarrow few collisions with background gas
- narrow optical transitions $\rightarrow \Delta\nu \leq 1 \text{ Hz}$
- long interrogation times $\rightarrow 0.1$ to 10 s; towards natural linewidth

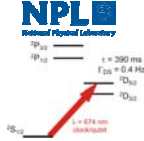
\Rightarrow ideal reference for frequency standard & clock

Review: H S Margolis, J Phys B **42**, 154017 (2009)

Choosing an ion reference

1. Identify species with a "long-lived" clock transition

- "forbidden" weak transition with metastable upper level
- $\Delta\nu = 1/2\pi\tau$ (lifetime τ ; natural linewidth $\Delta\nu$)
- for $0.1 \text{ s} \leq \tau \leq 100 \text{ s}$, $2 \text{ Hz} \leq \Delta\nu \leq 0.002 \text{ Hz}$

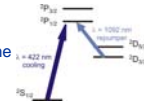


2. Examine sensitivities of transition energy to EM fields

- B-field (Zeeman shift), E-field (Stark shift),
- Blackbody radiation

3. Is there an accessible transition for laser-cooling?

- strong (S→P) dipole transition, short (~ns) P-state lifetime
- rapid scattering rate → efficient cooling



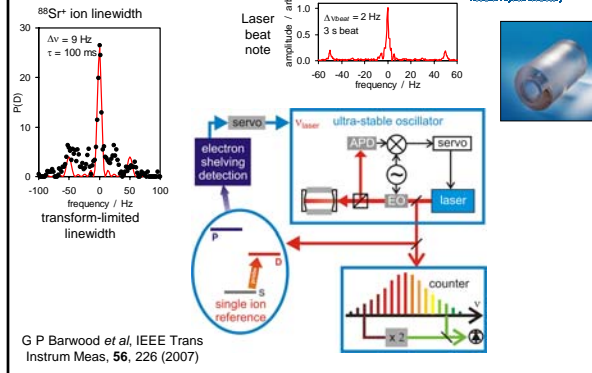
4. Can the cooling cycle be kept sufficiently closed?

- low branching-ratio for decay out of cooling cycle
- sensible lasers available for repumping?

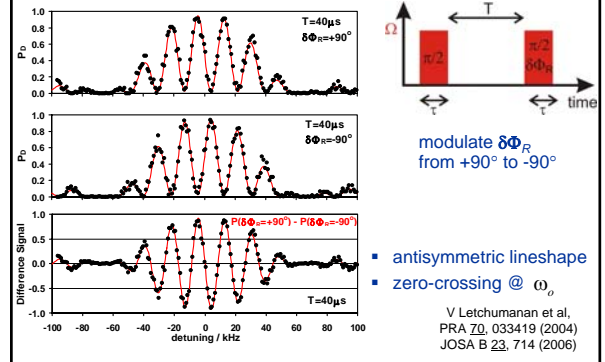
Which ion?

ion	λ_{clock} / nm	$\Delta\nu_{clock}$ / Hz	$\lambda_{cooling}$ / nm	$\Gamma_{cooling}$ / MHz	Cooling laser source / nm
⁸⁸ Sr ⁺	674	0.4	422	23	844 + shg
⁴⁰ Ca ⁺	729	0.15	397	23	397
¹⁷¹ Yb ⁺	436	3	369	20	738 + shg
¹⁷¹ Yb ⁺	467	~10 ⁻⁹	369	20	738 + shg
¹⁹⁹ Hg ⁺	282	1.7	194	70	shg + sfm
¹¹⁵ In ⁺	237	0.8	231	0.36	462 + shg
²⁷ Al ⁺	267	0.008	167	?	?

Architecture of a single-ion clock



Laser stabilisation

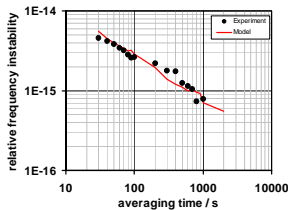


Comparing two traps

Two traps, each containing a single ion

- measure ν_{ion1}, ν_{ion2}

$$\text{calculate } \frac{\delta\nu}{\nu_o} = \frac{|\nu_{ion1} - \nu_{ion2}|}{\nu_o}$$

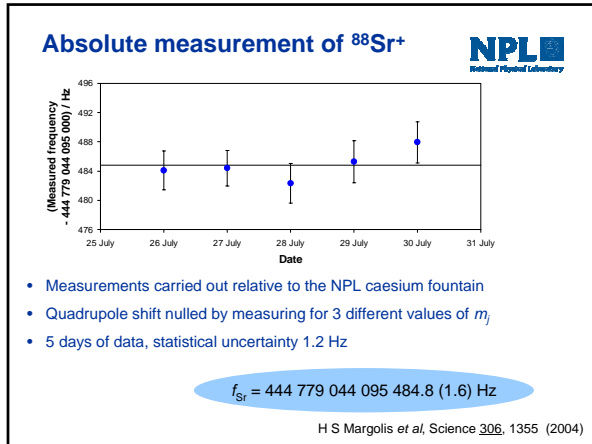


G P Barwood, G Huang, H A Klein, P Gill, NPL

Systematic uncertainties

Source	Method 1		Method 2	
	Shift (Hz)	Uncertainty (Hz)	Shift (Hz)	Uncertainty (Hz)
Statistics	-	1.3	-	1.2
Quadrupole shift	0	0.5	0	<0.01
2 nd order Doppler shift (micromotion)	<0.01	0.01	<0.01	0.01
2 nd order Doppler shift (secular motion)	<0.01	0.01	<0.01	0.01
Stark shift (micromotion)	+0.01	0.01	+0.01	0.01
Stark shift (secular motion)	<0.01	0.01	<0.01	0.01
Blackbody Stark shift	+0.30	0.08	+0.30	0.08
1092 nm ac Stark shift	0	0.02	0	0.02
422 nm ac Stark shift	+1.4	0.8	+1.4	0.8
Servo errors	-1.0	0.6	-0.4	0.3
Maser reference frequency	0	0.7	0	0.7
Gravitational shift	0	0.1	0	0.1
Total	+0.7	1.9	+1.3	1.6

H S Margolis *et al*, Science 306, 1355 (2004)



Absolute ν_{ion} measurements

ion	$\lambda_{\text{clock}} / \text{nm}$	$\Delta\nu_{\text{clock}} / \text{Hz}$	Fractional uncertainty $(\delta\nu/\nu) / 10^{-15}$	
$^{88}\text{Sr}^+$	674	0.4	3.8	NPL: H S Margolis <i>et al</i> , Science 306 , 1355 (2004)
$^{40}\text{Ca}^+$	729	0.15	2.4	Innsbruck: M Chwalla <i>et al</i> , PRL 102 , 023002 (2009)
$^{171}\text{Yb}^+$	436	3	1.1	PTB: Chr Tamm <i>et al</i> , PRA 80 , 043403 (2009)
$^{171}\text{Yb}^+$	467	$\sim 10^{-9}$	20	NPL: K Hosaka <i>et al</i> , PRA 79 , 033403 (2009)
$^{199}\text{Hg}^+$	282	1.7	0.65	NIST: W H Oskay <i>et al</i> , PRL 97 , 020801 (2006) J E Stalnaker <i>et al</i> , Appl Phys B 88 , 167 (2007)
$^{27}\text{Al}^+$	267	0.008	0.65	NIST: T Rosenband <i>et al</i> , Science 319 , 1808 (2008)

Al^+ : an useful reference?

Clock transition

- 267 nm: SHG of SHG of 1068 nm +
- linewidth: $\Delta\nu = 8 \text{ mHz}$ ++

Systematic frequency shift sensitivities

- smallest known blackbody shift ++
- negligible electric quadrupole shift ++
- linear Zeeman shift, average pair of components +
- Small quadratic Zeeman shift +

Cooling transition

- 167 nm: deep UV, not accessible ---

... need to overcome the cooling transition problem for cooling and state readout

4. Break?

Quantum logic spectroscopy

$\Psi_0 = |g\rangle_S |g\rangle_L |0\rangle_m$

Use logic ion to cool common mode m to ground state

P O Schmidt *et al*, Science **309**, 749 (2005)

Quantum logic spectroscopy

$\Psi_0 = |g\rangle_S |g\rangle_L |0\rangle_m$

Excite spectroscopy ion

$\Psi_1 = [\alpha |g\rangle_S + \beta |e\rangle_S] |g\rangle_L |0\rangle_m$

$\Psi_1 = [\alpha |g\rangle_S |0\rangle_m + \beta |e\rangle_S |0\rangle_m] |g\rangle_L$

P O Schmidt *et al*, Science **309**, 749 (2005)

Quantum logic spectroscopy

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$$\Psi_1 = [\alpha|g\rangle_s |0\rangle_m + \beta|e\rangle_s |0\rangle_m] |g\rangle_L$$

Apply π -pulse on RSB of spectroscopy ion

$$\Psi_2 = [\alpha|g\rangle_s |0\rangle_m + \beta|g\rangle_s |1\rangle_m] |g\rangle_L$$

$$\Psi_2 = |g\rangle_s |g\rangle_L [\alpha|0\rangle_m + \beta|1\rangle_m]$$

P O Schmidt *et al.*,
Science 309, 749 (2005)

Quantum logic spectroscopy

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$$\Psi_2 = |g\rangle_s |g\rangle_L [\alpha|0\rangle_m + \beta|1\rangle_m]$$

Apply π -pulse on RSB of logic ion

$$\Psi_3 = |g\rangle_s [\alpha|g\rangle_L + \beta|e\rangle_L] |0\rangle_m$$

P O Schmidt *et al.*,
Science 309, 749 (2005)

Quantum logic spectroscopy

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$$\Psi_3 = |g\rangle_s [\alpha|g\rangle_L + \beta|e\rangle_L] |0\rangle_m$$

Initial state of spectroscopy ion

Al+ Be+

$$\Psi_3 = \alpha|g\rangle_s + \beta|e\rangle_s$$

mapped to final state

$$\Psi_L = \alpha|g\rangle_L + \beta|e\rangle_L$$

of logic ion

..... readout state of logic ion with electron shelving method

P O Schmidt *et al.*,
Science 309, 749 (2005)

Al+ spectroscopy

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Observation of $^1S_0 \rightarrow ^3P_0$ transition

- QL spectroscopy for state readout
- $\Delta\nu = 8$ mHz
- first frequency measurement, $\delta\nu/\nu = 5 \times 10^{-15}$

T Rosenband *et al.*,
PRL 98, 220801 (2007)

Al+ precision

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Frequency ratio ν_{Al^+} / ν_{Hg^+}

- fractional uncertainty of 5.2×10^{-17}

T Rosenband *et al.*,
Science 319, 1808 (2008)

Two Al+ clock comparison

- relative stability $\sigma(\tau) = 2.8 \times 10^{-15} \tau^{-1/2}$
- fractional difference $|(v_{ion1} - v_{ion2}) / v_0| = 1.8 \times 10^{-17}$

C W Chou *et al.*,
PRL 104, 070802 (2010)

From the introduction.....Cs primary frequency standards

- based on 9.2 GHz hyperfine transition in ^{133}Cs atoms (fountain)
- accuracy $\sim 10^{-15}$ with >1 day of averaging time
- systematic $\delta\nu/\nu = 4.1 \times 10^{-16}$

..... the key to some new physics and a new definition of the SI second

Fine structure constant

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Frequency ratios (of different transitions) depend on α

- optical transitions have varying sensitivities to $\delta\alpha/\alpha$
- Measure frequency ratio over time yields $\dot{\alpha}/\alpha$

Frequency ratio ν_{Al^+} / ν_{Hg^+}

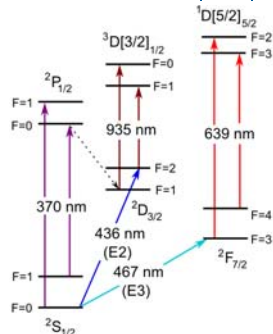
NIST: T Rosenband *et al.*,
Science 319, 1808 (2008)

$$\rightarrow \dot{\alpha}/\alpha = (-1.6 \pm 2.3) \times 10^{-17} / \text{yr}$$

2 clocks in one ion

Why $^{171}\text{Yb}^+$?

- E2 & E3 transitions have large and opposite sensitivities to any time variation of α
- any change in the optical frequency ratio amplifies greatly any change in α
- some systematic shifts (e.g. gravitational redshift, second-order Doppler shift) cancel exactly when ratio is measured in the same, single ion



NPL: R Godun, S King, & P Gill

Al⁺ : time dilation

NIST: C W Chou, D B Hume, T Rosenband, D J Wineland, Science **329**, 1630 (2010)

Relativistic time dilation

- ion stationary in clock #1
- ion oscillating \perp to laser in clock #2
- detect clock #2 advancing at slower rate for $5 \text{ m/s} < v_{rms} < 40$
- $\delta v/v_0 = -7 \times 10^{-15}$ @ $v_{rms} = 36 \text{ ms}$, and -4.5×10^{-16} @ $v_{rms} = 9 \text{ ms}$

Gravitational time dilation

- position of clock #1 fixed and compared to clock #2
- clock #2 height raised by 33 cm
- detect clock #2 advancing at faster rate: $\delta v/v_0 = (4.1 \pm 1.6) \times 10^{-16}$

Entanglement-enhanced precision

Limits on measurement precision

- Classical: shot noise limit

$$|\Psi_{in}\rangle = \frac{1}{\sqrt{2}}[|S\rangle + |D\rangle] \quad |\Psi_{out}\rangle = \frac{1}{\sqrt{2}}[|S\rangle + e^{i\phi}|D\rangle]$$

$$|\langle \Psi_{in} | \Psi_{out} \rangle|^2 = \cos^2(\phi/2) \quad \text{For } N \text{ repeat experiments: } \Delta\phi = 1/\sqrt{N}$$

- Quantum: Heisenberg limit

$$|\Psi_{in}\rangle = \frac{1}{\sqrt{2}}[|S_1\rangle|S_2\rangle \dots |S_N\rangle + |D_1\rangle|D_2\rangle \dots |D_N\rangle]$$

$$|\Psi_{out}\rangle = \frac{1}{\sqrt{2}}[|S_1\rangle|S_2\rangle \dots |S_N\rangle + e^{iN\phi}|D_1\rangle|D_2\rangle \dots |D_N\rangle]$$

$$|\langle \Psi_{in} | \Psi_{out} \rangle|^2 = \cos^2(N\phi/2) \quad \Delta\phi = 1/N: \quad \sqrt{N} \text{ enhancement}$$

V Giovannetti, S Lloyd, L Maccone, Science **306**, 1330 (2004)

More quantum metrology

Quantum metrology with entangled ions

- High fidelity entanglement on optical transition
- “Designer” atoms: engineered states for specific measurements

.... all the details from Christian Roos next week

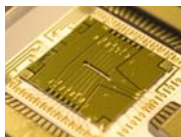
Summary.... microtraps

Scaling up to ion arrays: the DiVincenzo scalability criterion

- Many different technical approaches
- 2D & 3D electrode geometries
- All with microfabrication challenges
- Optical integration is a further challenge

Case-study of NPL microtrap: Au-on-SiO₂-on-Si

- Monolithic, 3D, unit aspect ratio
- Deep potential, long storage times
- Good motional frequencies
- Good electrical characteristics
- Low ion-heating rate



Summary.... metrology

Atomic clocks

- Clock architecture: reference, oscillator, counter
- Optical references & clocks: increased precision
- Single-ion clock components
- Evaluation, systematics, and absolute measurements

Quantum logic spectroscopy

- Powerful technique using QIP-style state mapping
- Used to detect Al clock transition
- Perform metrology at 17th decimal place
- Exciting time for studying physics with unprecedented precision
- the route to redefining definition of time